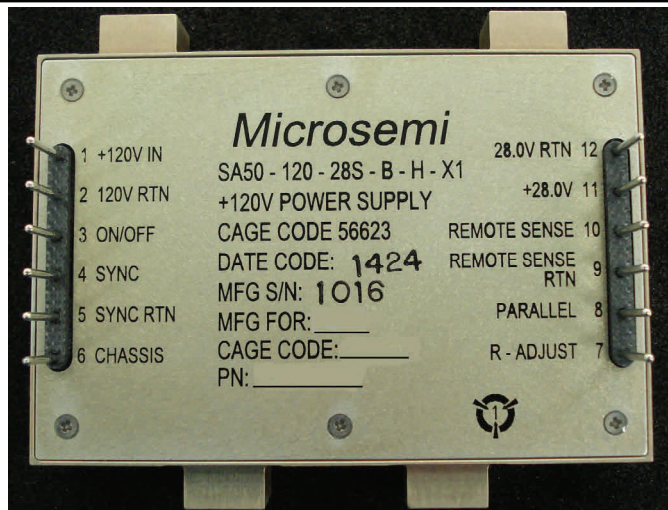


**RADIATION HARDENED
ISOLATED DC/DC CONVERTERS****SA50-120****50 Watts Total Power****120 V_{DC} IN — 28V, 15V or 12V_{DC} OUT****DESCRIPTION**

The SA series of DC-DC converters are designed for the rigors of space, characterized for Total Ionizing Dose and Single Event Effects. Operating at a fixed frequency of 220 kHz, the SA family of parts can be externally synced with other frequency sources. The SA50 contains an internal EMI filter making it compliant to Mil Std 461 emissions and susceptibility. The SA50-120 Series of converters are designed for use in the International Space Station or direct connect to Satellite Solar Panels. For custom input voltages, please contact PMG for a quote.

Microsemi Space & Power Management (SPM) has achieved decades of flawless execution in harsh space environments. PMG's heritage, producing complex custom (radiation hardened) switching power designs and systems is now complimented with the "SA Series" Standard Radiation Hardened DC/DC converter modules. The same rigorous design methodology employed for custom designs has been applied to the SA Family of standard products. These space grade inverters are ideal choices for decades to come. Export license may be required for foreign shipments.

**FEATURES**

- **+120 V_{DC} Satellite Input Interface**
- **100kRad (Si) TID; Single Event Effect rated**
- **Surface Mount Construction (non-hybrid)**
- **50W total power, high efficiencies 85%+**
- **Patented Magnetic Feedback**
- **Isolated Synchronization Input**
- **Adjustable Output**
- **Modules can be tied in Parallel**
- **Primary referenced ON - OFF command**
- **Over-current Protection**
- **Input Under-voltage lockout**
- **MIL-STD-1547B design de-rating criteria**
- **100% Space level Environmental Screening**
- **Standard Mounting 2.05" x 3.05" x 0.475"**
- **Multiple Single Output Voltage Options**
- **SEE > 80 MeV•cm² /mg Version Available**
- **EMI Compliance to MIL-STD-461**

ELECTRICAL PARAMETERS

Absolute Maximum Ratings		Recommended Operating Conditions	
VIN range	-0.5Vdc to +158Vdc	VIN range	+86Vdc to +158Vdc
Output power	50 Watts	VIN range ^a	+86Vdc to +120Vdc
Lead temperature	+300°C for 10 Sec.	VIN range ^b	+86Vdc to +100Vdc
Operating temperature	-55°C to +125°C	VIN range ^d	+86Vdc to +135Vdc
Storage temperature	-55°C to +125°C	Output power	2 watts to Max. Rated
Shock	1500 gpk, 0.5 msec, ½ sine	Operating temperature ^c	-55°C to +125°C
Constant Acceleration	50 g	Operating temperature ^{a,b}	-55°C to +70°C
Random Vibration	24.06 grms , 50-2000 Hz		

a Meets derating per MIL-STD-975M

b Meets derating per MIL-STD-1547B

c For operation at +125°C see table Note 15

d Single Event Effect compliant

ELECTRICAL PARAMETERS

SA50-120-28S

Parameter	Group A Subgroup 1 25°C 2 -55°C 3 85°C	Conditions, unless otherwise specified -55°C ≤ TCASE ≤ +85°C VIN = 120V DC ± 5%, CL = 0, No Sync	Limits			Unit
			Min	Nom	Max	
Input Voltage	1,2,3	Note 2	86	120	158	V
Output Voltage (VOUT)						
	1	IOUT = 100% rated load, Note 5	27.89	28.00	28.11	V
	2,3	IOUT = 100% rated load, Note 5	27.73	28.00	28.27	V
Output Voltage Adjust (Vadj)						
	1,2,3	VIN = 60, 100, 125 Volts % relative to nominal output voltage	±10			%
Output Power (POUT)	1,2,3	VIN = 86, 120, 158 Volts, Notes 2,4	5		50	W
Output current (IOUT)						
	1,2,3	VIN = 86, 120, 158 Volts, Notes 2,3,4,5	0.2		1.8	A
Line regulation (VRLINE)						
	1,2,3	VIN = 86, 120, 158 Volts IOUT =10%, 50%, 100% rated, Notes 5, 14	-56		56	mV
Load regulation (VRLOAD)						
	1,2,3	VIN = 86, 120, 158 Volts IOUT =10%, 50%, 100% rated, Note 5, 13	-280		280	mV
Input current (IIN)	1,2,3	IOUT = 0, Pin 3 open		7	25	mA
		Pin 3 shorted to pin 2		3	5	
Output ripple (VRIP)						
	1,2,3	VIN = 86, 120, 158 Volts IOUT = 100% rated load, Notes 5, 6		100	280	mV p-p
Switching frequency (FS)	1,2,3	Sync. Input (Pin 4) open	200	220	240	kHz
Efficiency (EFF)	1,2,3	IOUT = 100% rated load, Note 5	[79] 82	[82] 85		%
Inhibit Input						
ON voltage (or Open Collector)		Note 1	4.5			V
OFF drive current (sink)			1000			μA
OFF voltage					2	V

ELECTRICAL PARAMETERS

SA50-120-28S

Parameter	Group A Subgroup 1 25°C 2 -55°C 3 85°C	Conditions -55°C ≤ TCASE ≤ +85°C VIN = 120V DC ± 5%, CL = 0 unless otherwise specified	Limits			Unit
			Min	Nom	Max	
Synchronization Input						
frequency range		Ext. Clock on Sync. Input (Pin 4) Note 1	500		600	kHz
pulse high level			4.0		10.0	V
pulse low level			-0.5		0.5	V
pulse transition rate			200			V/μs
pulse duty cycle			10		80	%
Current Limit Point Expressed as a % of full rated output current	1,2,3	VOUT = 90% of Nominal, Note 5	105		135	%
Power dissipation, load fault (PD)	1,2,3	Short Circuit, Overload, Note 8			18	W
Output response to step load changes (VTLD)		Half Load to/from Full Load, Notes 4,5,6,5,9	-1680		1680	mV pk
Recovery time, step load changes (TTLD)		Half Load to/from Full Load, Note 4,5,6,9,10		200	2000	μs
Output response to step line changes (VTLN)		86V to/from 158V IOUT = 100% rated load, Notes 1, 5,11	-1000		1000	mV pk
Recovery time, step line changes (TTLN)		86V to/from 158V IOUT = 100% rated load, Notes 1, 5,11		200	2000	μs
Turn-on Response						
Overshoot (VOS) (main)		No Load, Full Load Notes 4,5,6,12			2800	mV
Turn-on Delay (TDLY)			0.1		10.0	mSec
Capacitive Load (CL)						
		IOUT = 100% rated load, No effect on DC performance, Notes 1, 5, 7			200	μF
Line Rejection		DC to 50KHz, Notes 1, 5 IOUT = 100% rated load	30	60		dB
Isolation	1	Input (Pins 1,2,3) to Outputs Any Pin to Case (except pin 6) Sync and Sync Rtn to any pin and case	100			MΩ
Device Weight		Standard Case Style A			110	g
		Case Style B			120	
MTBF		MIL-HDBK-217F2, SF, 35°C		8.22E+06		Hrs

ELECTRICAL PARAMETERS

SA50-120-15S

Parameter	Group A Subgroup 1 25°C 2 -55°C 3 85°C	Conditions, unless otherwise specified -55°C ≤ TCASE ≤ +85°C VIN = 120V DC ± 5%, CL = 0, No Sync	Limits			Unit
			Min	Nom	Max	
Input Voltage	1,2,3	Note 2	86	120	158	V
Output Voltage (VOUT)						
SA50-120-15S	1	IOUT = 100% rated load, Note 5	14.74	15.00	15.06	V
	2,3	IOUT = 100% rated load, Note 5	14.85	15.00	15.15	V
Output Voltage Adjust (Vadj)						
	1,2,3	VIN = 60, 100, 125 Volts % relative to nominal output voltage	±10			%
Output Power (POUT)	1,2,3	VIN = 86, 120, 158 Volts, Notes 2,4	5		50	W
Output current (IOUT)						
	1,2,3	VIN = 86, 120, 158 Volts, Notes 2,3,4,5	0.2		3	A
Line regulation (VRLINE)						
	1,2,3	VIN = 86, 120, 158 Volts IOUT = 10%, 50%, 100% rated, Notes 5, 14	-30		30	mV
Load regulation (VRLOAD)						
	1,2,3	VIN = 86, 120, 158 Volts IOUT = 10%, 50%, 100% rated, Note 5, 13	-150		150	mV
Input current (IIN)	1,2,3	IOUT = 0, Pin 3 open Pin 3 shorted to pin 2		10 3	25 5	mA
Output ripple (VRIP)						
	1,2,3	VIN = 86, 120, 158 Volts IOUT = 100% rated load, Notes 5, 6		75	150	mV p-p
Switching frequency (FS)	1,2,3	Sync. Input (Pin 4) open	200	220	240	kHz
Efficiency (EFF)	1,2,3	IOUT = 100% rated load, Note 5	[79] 82	[82] 85		%
Inhibit Input						
ON voltage (or Open Collector)		Note 1	4.5			V
OFF drive current (sink)			1000			μA
OFF voltage					2	V

ELECTRICAL PARAMETERS

SA50-120-15S

Parameter	Group A Subgroup 1 25°C 2 -55°C 3 85°C	Conditions -55°C ≤ TCASE ≤ +85°C VIN = 120V DC ± 5%, CL = 0 unless otherwise specified	Limits			Unit
			Min	Nom	Max	
Synchronization Input						
frequency range		Ext. Clock on Sync. Input (Pin 4) Note 1	500		600	kHz
pulse high level			4.0		10.0	V
pulse low level			-0.5		0.5	V
pulse transition rate			200			V/μs
pulse duty cycle			10		80	%
Current Limit Point Expressed as a % of full rated output current	1,2,3	VOUT = 90% of Nominal, Note 5	105		135	%
Power dissipation, load fault (PD)	1,2,3	Short Circuit, Overload, Note 8			18	W
Output response to step load changes (VTLD)		Half Load to/from Full Load, Notes 4,5,6,5,9	-940		940	mV pk
Recovery time, step load changes (TTLD)		Half Load to/from Full Load, Note 4,5,6,9,10		200	2000	μs
Output response to step line changes (VTLN)		86V to/from 158V IOUT = 100% rated load, Notes 1, 5,11	-630		630	mV pk
Recovery time, step line changes (TTLN)		86V to/from 158V IOUT = 100% rated load, Notes 1, 5,11		200	2000	μs
Turn-on Response						
Overshoot (VOS) (main)		No Load, Full Load Notes 4,5,6,12			2800	mV
Turn-on Delay (TDLY)			0.1		10.0	mSec
Capacitive Load (CL)						
		IOUT = 100% rated load, No effect on DC performance, Notes 1, 5, 7			350	μF
Line Rejection		DC to 50KHz, Notes 1, 5 IOUT = 100% rated load	30	60		dB
Isolation	1	Input (Pins 1,2,3) to Outputs Any Pin to Case (except pin 6) Sync and Sync Rtn to any pin and case	100			MΩ
Device Weight		Standard Case Style A			110	g
		Case Style B			120	
MTBF		MIL-HDBK-217F2, SF, 35°C		8.22E+06		Hrs

ELECTRICAL PARAMETERS

SA50-120- all versions

Radiation Tests				
Test	Conditions	Min	Typ	Unit
Total Ionizing Dose (Gamma)	MIL-STD-883, Method 1019 Operating bias applied during exposure,	100 {60}	300	KRad (Si)
Dose Rate (Gamma Dot)	MIL-STD-883, Method 1023 Operating bias applied during exposure,	1E8		Rad (Si)
Temporary Saturation Survival	Full Rated Load, VIN = 70V	4E10	1E11	/sec
Neutron Fluence	MIL-STD-883, Method 1017	8E12	1E13	Neutrons
Single Event Effects SEU, SEL, SEGR, SEB	Heavy ions (LET) Operating bias applied during exposure, Full Rated Load, VIN = 70V, Note 5	35 {35} [82]	39.7 {39.7} [86]	MeV•cm2 /mg

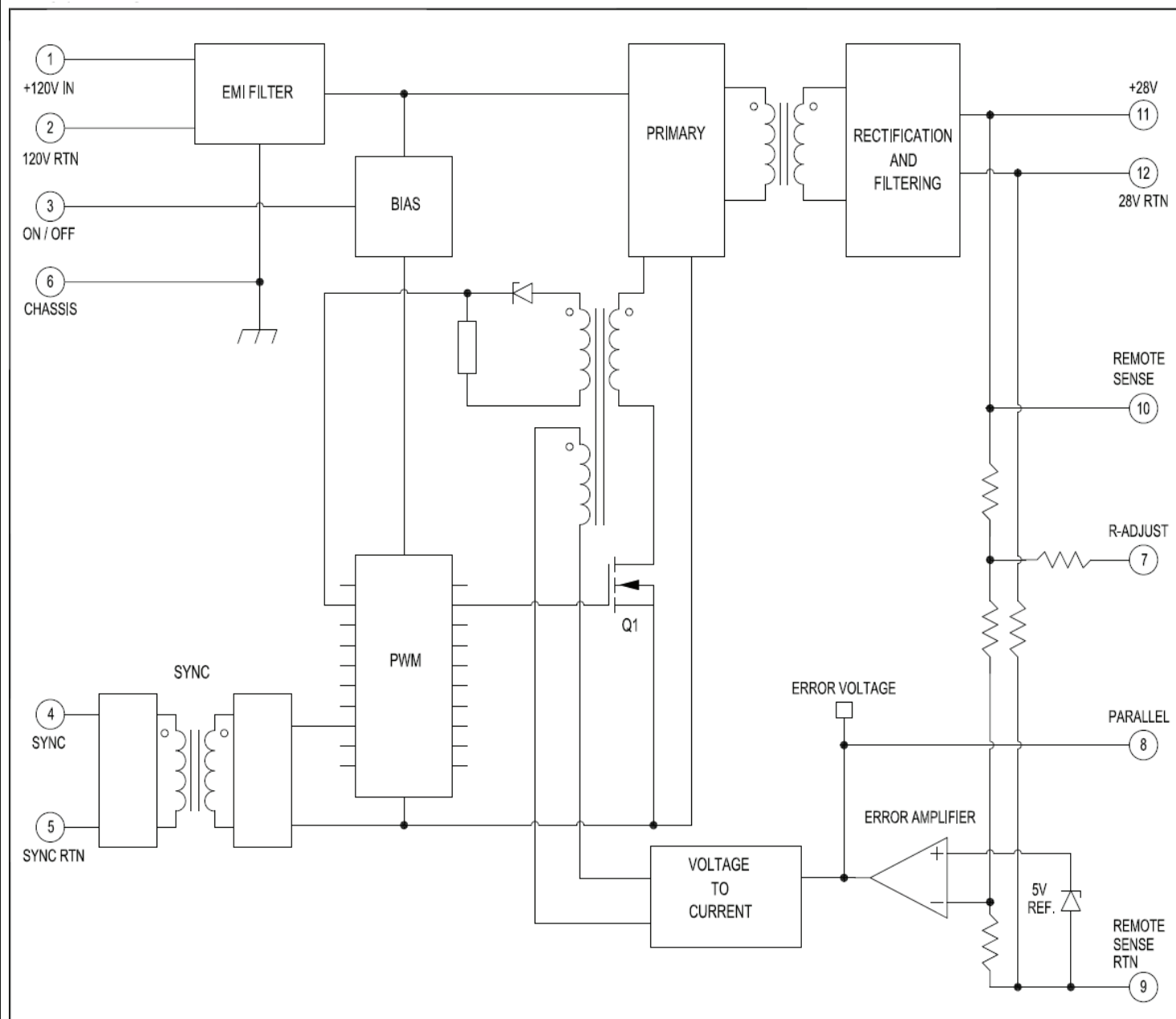
Notes: Electrical Performance Characteristics

- Parameter guaranteed by design.
- Parameter verified during line and load regulation tests. Regulation is specified for 10% to 100% loading on all outputs.
- Does not apply to single output version
- Does not apply to single output version
- Unless otherwise specified, "Rated" load is 50W on the main output. Values in { } brackets reflect "-L" option TID Limited version performance. Values in [] brackets reflect "-H" option SEE hardened version performance. The "-H" option incorporates alternative FET technologies providing a >82 MeV•cm2 /mg (Gold Ion) SEE capability to the design.
- Guaranteed for a D.C. to 20MHz bandwidth. Tested using a 20kHz to 10MHz bandwidth.
- Capacitive load may be any value from 0 to the maximum limit without compromising dc performance. A capacitive load in excess of the maximum limit may interfere with the proper operation of the converter's overload protection, causing erratic behavior during turn-on.
- Overload power dissipation is defined as the device power dissipation with the load set such that VOUT = 90% of nominal.
- Load step transition time $\geq 10 \mu s$.
- Recovery time is measured from the initiation of the transient to where VOUT has returned to within $\pm 1\%$ of its steady state value.
- Line step transition time $\geq 100 \mu s$.
- Turn-on delay time from either a step application of input power or a logic low to a logic high transition on the inhibit pin (pin 3) to the point where VOUT = 90% of nominal.
- Load Regulation relative to output voltage at 50% rated load.
- Line Regulation relative to output voltage at 120Vdc input.
- For operation at temperatures between +85°C and +125°C, derate power linearly from 50 watts to zero. Parameter limits are not guaranteed.

Analyses & Reports

- 1: Structural Analysis
- 2: Stress Analysis
- 3: Thermal Analysis
- 4: Radiation Analysis
- 5: Worse Case Analysis
- 6: Reliability Analysis
- 7: FEMA
- 8: First Article Qualification Test Report
- 9: EMI Test Report

TYPICAL BLOCK DIAGRAM



Typical Block Diagram for the SA50-120 Single Output family of parts.

Pins 11 & 12: Output voltage for individual family members.

THEORY OF OPERATION

Input voltage is applied to the input EMI filter. This filter consists of differential and common mode components that attenuate the internal converter switching noise. The internal EMI filter attenuates conducted emissions to ensure compliance to MIL-STD-461 levels.

Internal controller bias is supplied during power up and in over-current scenarios via Darlington startup transistors off the input line. The controller power supply ramps up to the turn on point where it starts to supply drive to the main power converter MOSFET Q1. Under normal load conditions the output voltage will come up and a “Bootstrap” voltage is fed back to stabilize the Bias supply eliminating power loss in the start-up transistors.

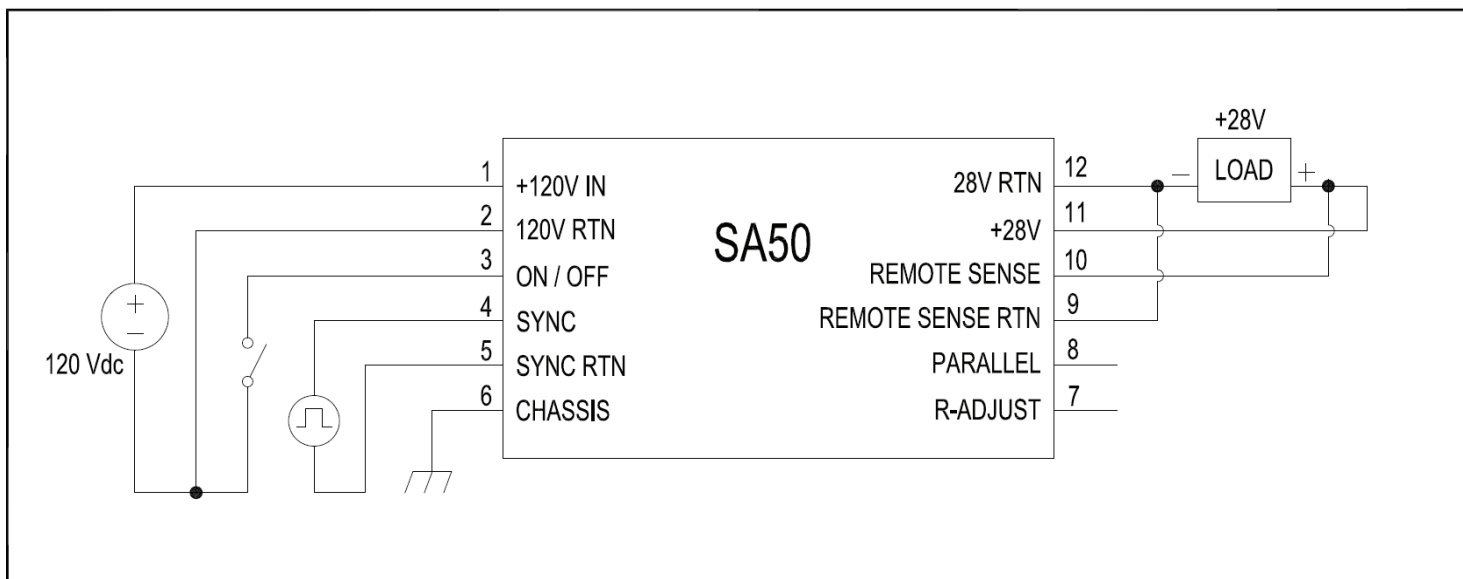
Main power conversion occurs in the forward converter Q1 and associated Transformer. The secondary windings develop the required output voltages in parallel. A coupled inductor promotes good output cross regulation. Elimination of secondary side post regulators promotes high efficiency performance.

Output voltages are regulated on the main output secondary side. A TL1431 reference develops a current mode error signal which is chopped by the main forward transformer voltage and the summed with the primary side converter current in a patented magnetic feedback approach. The combined “V + I” error signal is applied to the primary controller’s ramp control input to complete the regulation loop.

The primary ON OFF command disables internal switch-mode action when pulled low.

The SYNC input is fully transformer isolated to allow operation from primary or secondary referenced sync drives.

TYPICAL CONFIGURATION DIAGRAM



SA50-120-28S

Pin #	Designation	Pin #	Designation
1	+120V IN	7	R-ADJUST
2	+120V RTN	8	PARALLEL
3	ON/OFF	9	REMOTE SENSE RTN
4	SYNC	10	REMOTE SENSE
5	SYNC RTN	11	+28V
6	CHASSIS	12	+28V RTN

SA50-120-15S

Pin #	Designation	Pin #	Designation
1	+120V IN	7	R-ADJUST
2	+120V RTN	8	PARALLEL
3	ON/OFF	9	REMOTE SENSE RTN
4	SYNC	10	REMOTE SENSE
5	SYNC RTN	11	+15V
6	CHASSIS	12	+15V RTN

Typical Connection Diagram for the SA50-120 Single Output family of parts.

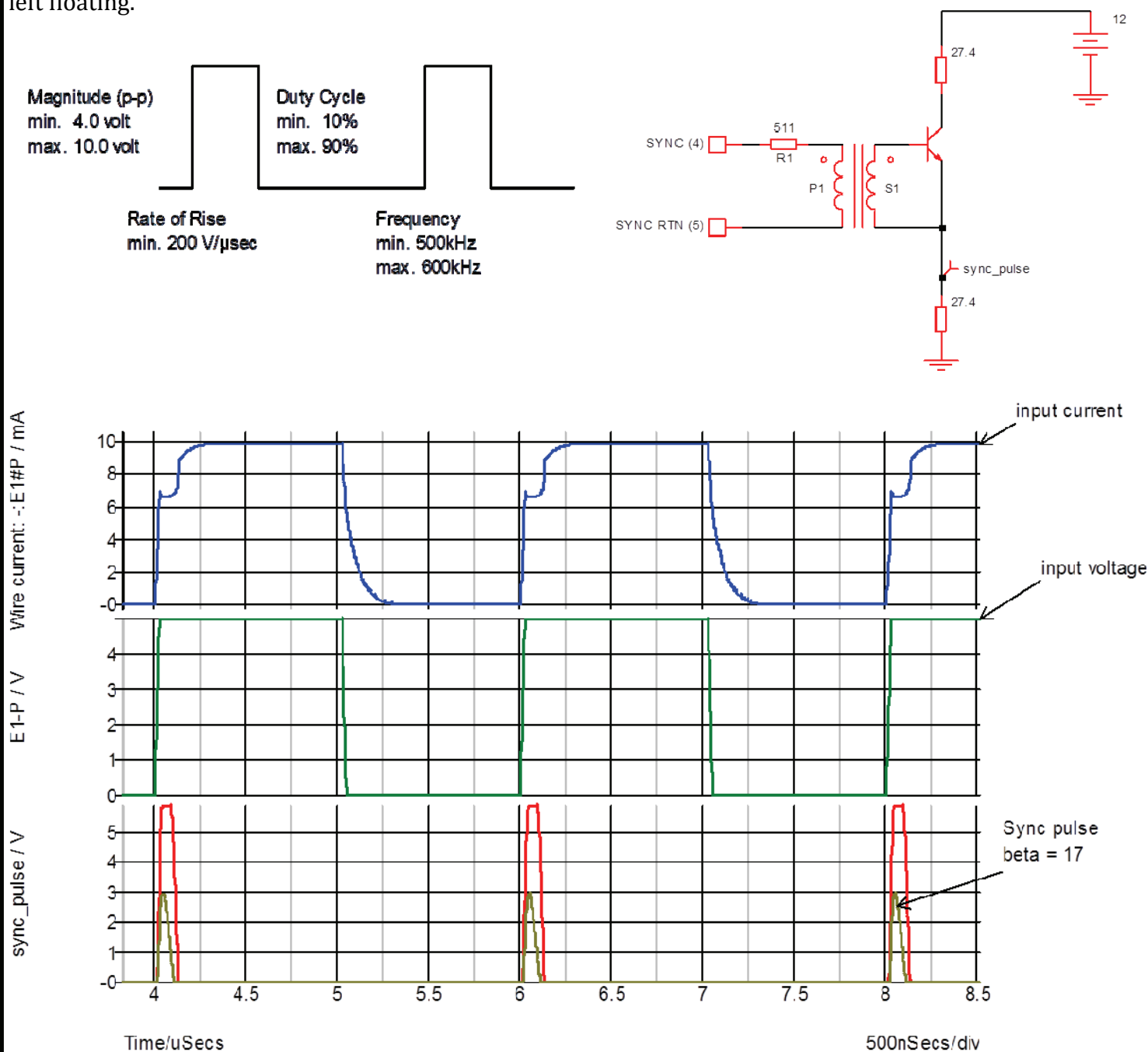
Pins 11 & 12: Output voltage for individual family members.

Short Circuit / Over Current Limit

The output current is limited by the built in current limit circuit, to protect the Power Supply and the load from over-stress. The converter continues to regulate its output voltage under this loading condition. If the load impedances of any of the outputs are further decreased, the converter turns off and attempts to restart after a delay.

Sync Input:

The Power Supply's internal clock may be synchronized to an external signal. For enhanced system configuration flexibility and noise immunity, the sync input circuit is magnetically isolated from all other circuits and chassis. The interface is shown below. The circuit operates from the rising (leading) edge of the sync waveform, that generates a short synchronization pulse to the PWM controller. Note that the sync circuit DC input resistance is 500 Ohms. Specifically, the circuit driving the sync input needs to deliver a minimum of 5 mA of current into the input for a minimum of 50 ns, resulting in a minimum reflected voltage of 4 volts. Higher voltage drives are acceptable up to 10 volts, delivering approximately proportional higher current levels. Maintenance of high level voltage drive beyond 50 ns is not essential for correct synchronization function. If the Sync Input is not used, one sync pin should be tied to chassis ground, the other pin left floating.



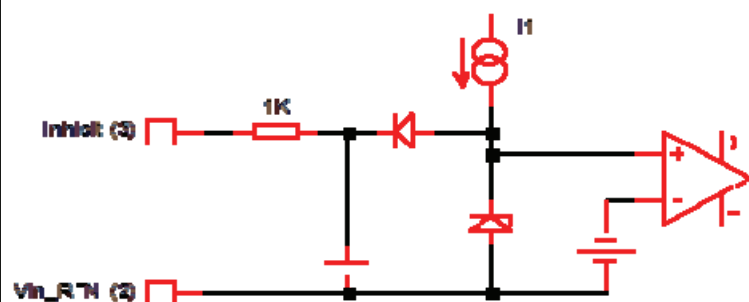
APPLICATION DATA

Under Voltage Operation

The Input Under-voltage protection feature prevents operation at an undesirably low input voltage. The outputs are guaranteed to turn on at the specified minimum input voltage and guaranteed to be disabled below 70% of the specified minimum input voltage.

Inhibit Function

An external inhibit port is provided to control converter operation. The inhibit circuit is referenced to the DC Input return. The interface is as shown below. The inhibit signal may be an open-collector or TTL type. Interface must sink 5 mA minimum to inhibit the output.



Inhibit Pin	Power Supply Output
Open	ON
> 4.5 volt	ON
Short	OFF
< 3.0 volt	OFF

Parallel Operation

The output terminals of up to 5 modules may be connected in parallel.

The expected current sharing accuracy is 10% at maximum load.

To insure current sharing, the Parallel terminal of every Power Supply module must be connected together to form a common buss.

These connections should be made relatively short, but can be made in any configuration.

The remote sense terminals may remain unconnected. For best output voltage regulation however, the remote sense terminal of each of the paralleled set of Power Supplies should be connected to a single point, as close as possible to the positive load terminal or point where the voltage regulation is desired to be maintained.

Similarly, the remote sense return terminal of each Power Supply should be connected to a single point, as close as possible to the negative load terminal.

The R-ADJUST function may be used in a system of paralleled modules.

The sync function is described in the application notes.

The specified sync input signal may be applied to each of the paralleled modules.

For best performance, phase shift the sync signal between modules.

The sync functionality remains the same for a system of paralleled modules.

The use of the sync function is optional for single and or paralleled operation.

The specified sync input signal may be applied to any one of the paralleled modules.

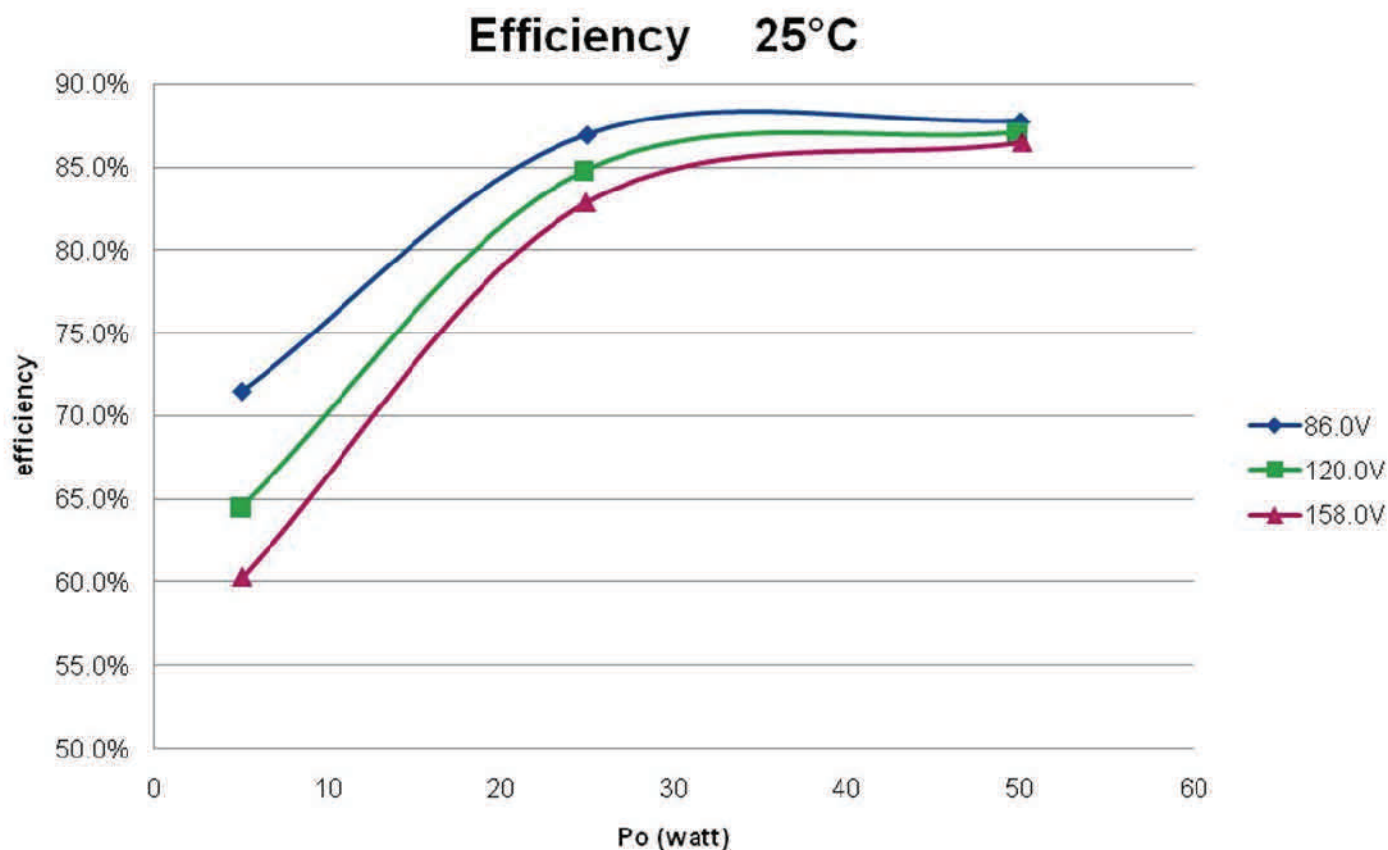
QUALIFICATION TESTS

QUALIFICATION TESTS			
Test 1	Test Method/Condition	Custom Qualification Method	Reference
External Visual	Yes per O&M – dimensions and mass or std 883 2009	Inspection	Test Report
Electrical	Read & Record (-55 °C, +25 °C, +85 °C)	Test	Test Report
Shock, Non-Operating	MIL-STD-202, Method 213B, Test Condition F, 1500 gpk, 0.5 msec ½ sine pulse. Three pulses in each direction of each axis, 18 pulses total.	Similarity	QTR996 Appendix B
Vibration, Operating	MIL-STD-202, Method 214A, Cond. II-F, 24.06 grms random vibration, 50-2000 Hz, 3 minutes/axis, 9 min total. Outputs monitored.	Similarity	QTR996 Appendix C
Thermal Vacuum	MIL-STD-883, Meth 1001, Cond G, 3 cycles with base plate temperature of -55 °C to +85 °C. Outputs monitored during TVAC cycles, record at temperatures noted under Electrical.	Similarity	QTR996 Appendix D
Temperature Cycling	100 cycles from base plate temperature, MIL-STD-883, Method 1010.8, Cond A, -55 °C to +90 °C, 10-15 C°/min, 10 min dwell at temperature limits. Outputs monitored during thermal cycles.	Similarity	QTR996 Appendix D
EMI - Unit to be characterized to these requirements (Not pass/fail)	CE101, CE102, CE106, CS101, CS103, CS104, CS105, CS109, CS116, RE101, RE102, RE103, RS103, Radiated Susceptibility Magnetic Field 10 nT Magnetic Moment 300 A-m2. MIL-STD-461 setup per MIL-STD-462	Test	CE101, CE102, CE106, CS101, CS103, CS104, CS105, CS109, CS116, RE101, RE102, RE103, RS103
External	No Damage	Similarity	QTR996
Visual Inspection		Similarity	QTR996
Electrical	Read & Record at +25 °C	Similarity	QTR996
Steady State Life test	1000 Hours@ Tc= +105 °C	Similarity	QTR996
End Point Electricals	Read & Record (-55 °C, +25 °C, +85 °C)	Similarity	QTR996

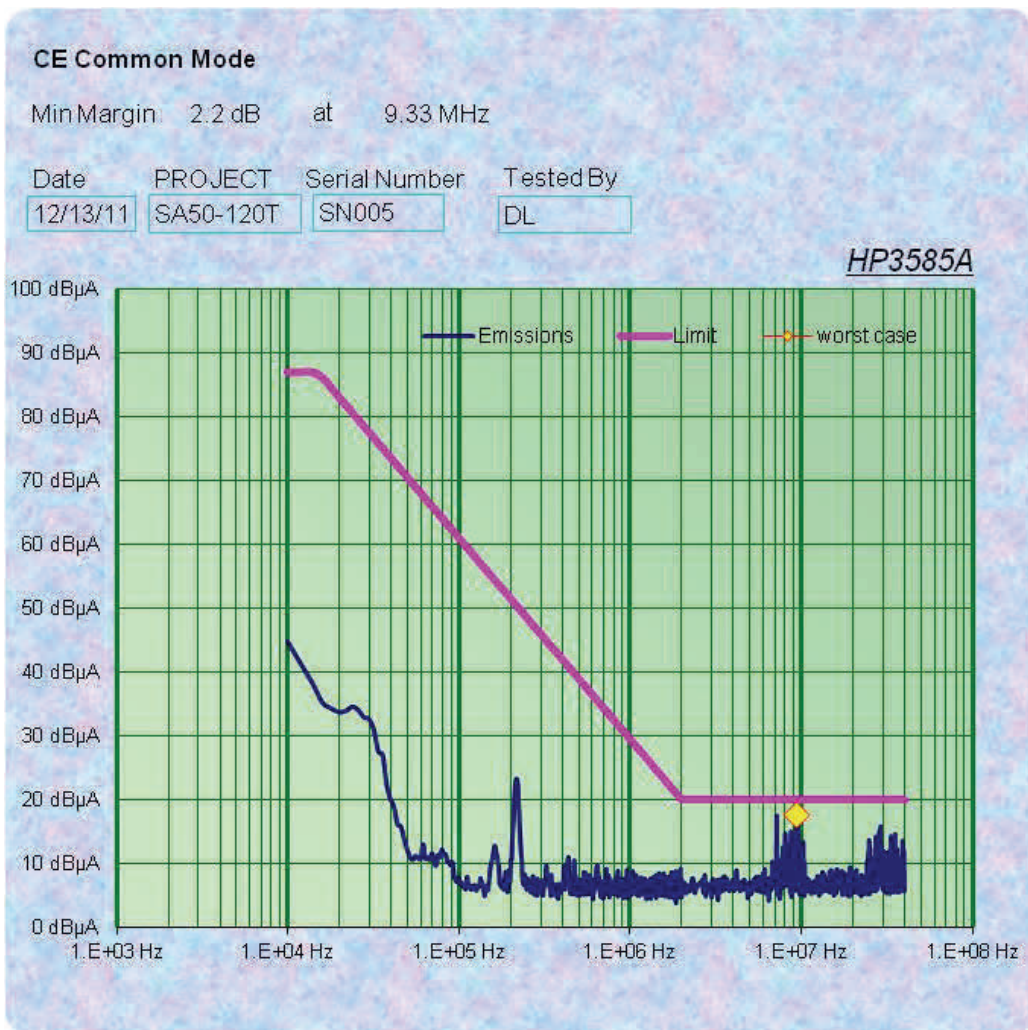
1. Electrical test at +25°C shall be performed unless otherwise specified after each Environmental test (Shock, Vibration, Temperature cycle, EMI and Life)

RADIATION

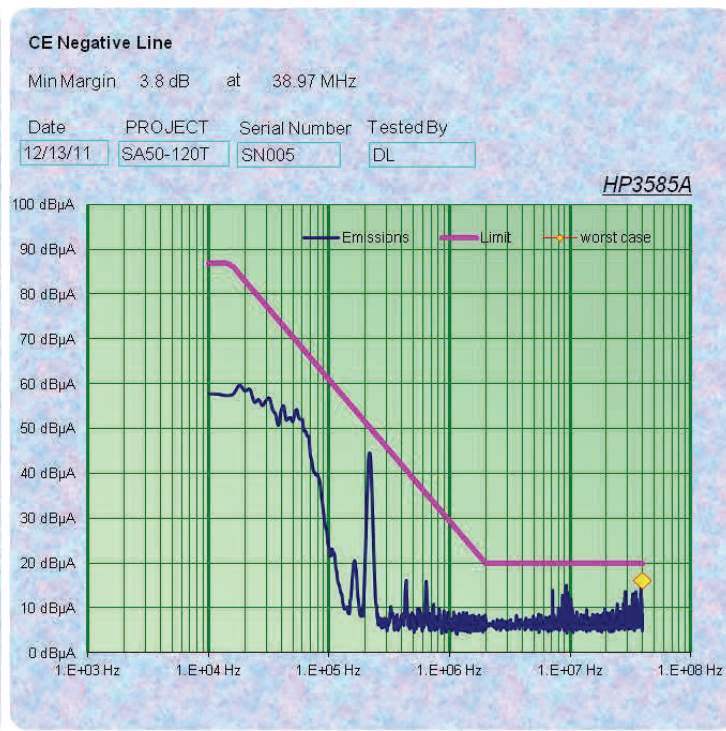
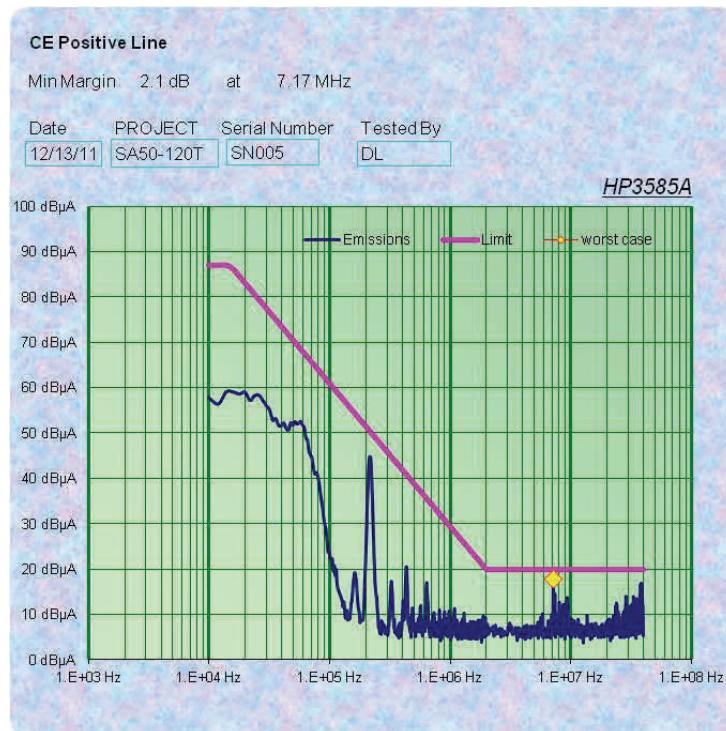
Total Dose	100 krad, MIL-STD-883, Method 1019 Operating bias applied during exposure, Full Rated Load, VIN = 120 V	Similarity	RPT603
SEE (Analysis)	82 MeV•cm ² /mg , Heavy ions (LET) Operating bias applied during exposure, Full Rated Load, VIN = 120 V	Similarity	RPT603
ELDRS (Analysis)	40 krad, MIL-STD-883, Method 1019, Condition DD of MIL-STD-883 Method 1019.	Similarity	RPT603
Neutron Fluence (Analysis)	8E12 Min to 1E13 Typ. MIL-STD-883, Method 1017	Similarity	RPT603
Dose Rate (Gamma Dot) (Analysis) Temporary Saturation	MIL-STD-883, Method 1023 Operating bias applied during exposure, Full Rated Load, VIN = 120V	Similarity	RPT603



EMI - Differential Mode Conducted Emissions (CE102)



MIL-STD-461D EMI Characterization



ATP Testing - Extended Screening

Requirement	Test Method /Condition
External Visual	O&M –dimensions and mass
Initial Electrical	Full performance at +25°C
Vibration	Workmanship operating vibration (outputs monitored) MIL-STD-202, Method 214 6 grms (50 Hz-2 kHz) 1 minute perpendicular to the board
Post Vibration Electrical	Full performance at +25°C
Temperature Cycle	MIL-STD-883, Method 1010, Cond. A, 10 cycles, +85°C to -55°C, operating. Outputs monitored during Thermal cycles
Burn-in	160 Hrs @ 105°C, 50% of rated load (outputs monitored)
Final Electrical	Full performance at -55°C +25°C +85°C (deliverable data)
External Visual	No Damage

ATP Testing - Standard Screening

Requirement	Test Method /Condition
External Visual	O&M –dimensions and mass
Initial Electrical	Full performance at +25°C
Vibration	Workmanship non-operating vibration MIL-STD-202, Method 214, 6 grms (50 Hz-2 kHz) 1 minute perpendicular to the board
Post Vibration Electrical	Full performance at +25°C
Temperature Cycle	MIL-STD-883, Method 1010, Cond. A, 1 cycle, +85°C to -55°C, operating. Outputs monitored during Thermal cycles
Burn-in	40 Hrs @ 105°C, 50% of rated load (outputs monitored)
Final Electrical	Full performance at +25°C (deliverable data)
External Visual	No Damage

ATP Testing - Standard Screening Prototypes

Requirement	Test Method /Condition
External Visual	O&M –dimensions and mass
Electrical	Full performance at +85°C, +25°C, -55°C for initial first article of
	Full Performance at +25°C for previously qualified variation of the SA50.
Vibration	None
Temperature Cycle	None
Burn-in	None
External Visual	No Damage

Extended Screening: Microsemi PMG can perform additional tests as defined by customer requirements. Please contact the PMG sales contact shown on the last page of this datasheet for a quote on your specific needs.

MECHANICAL INTERFACE - "A" Package

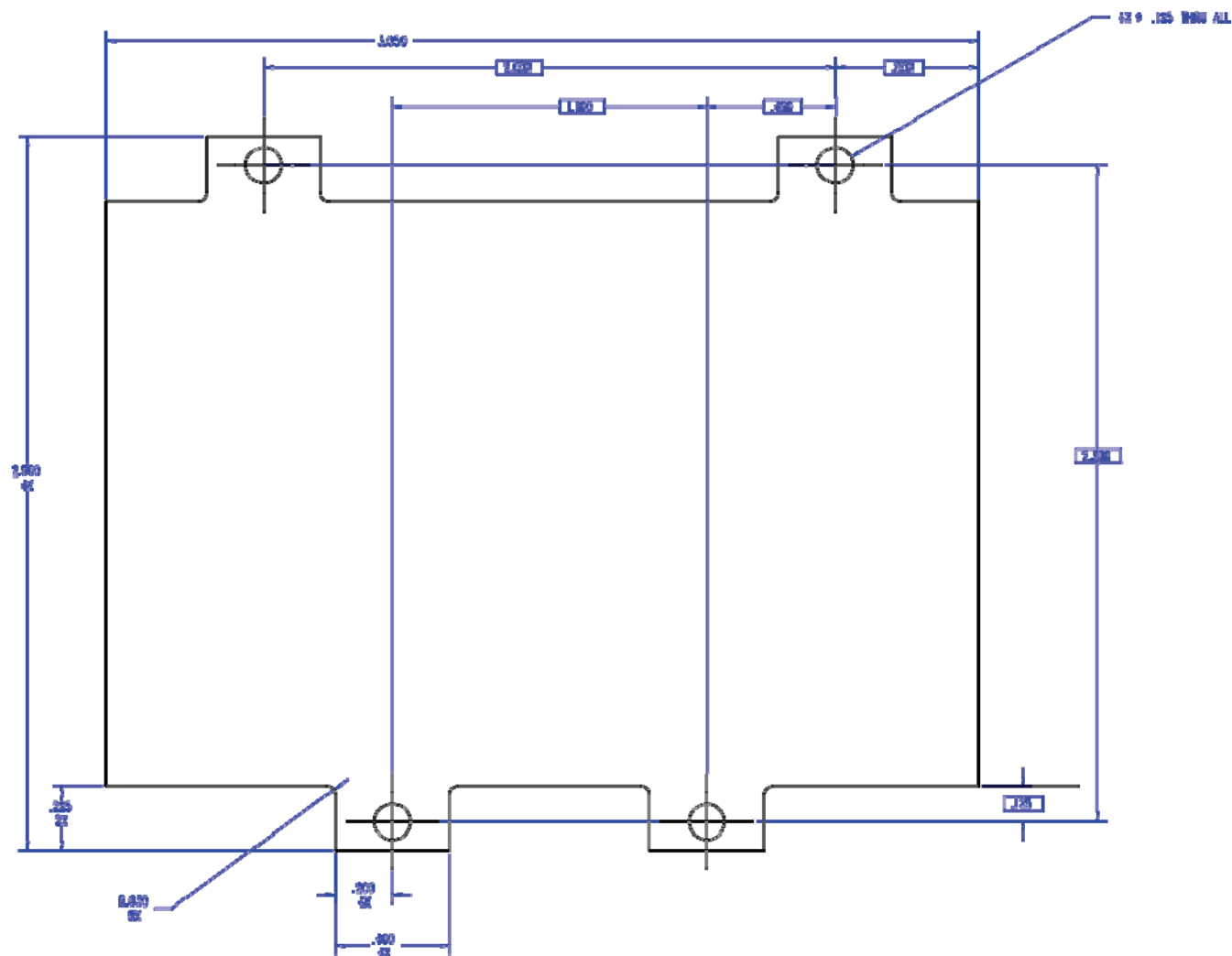
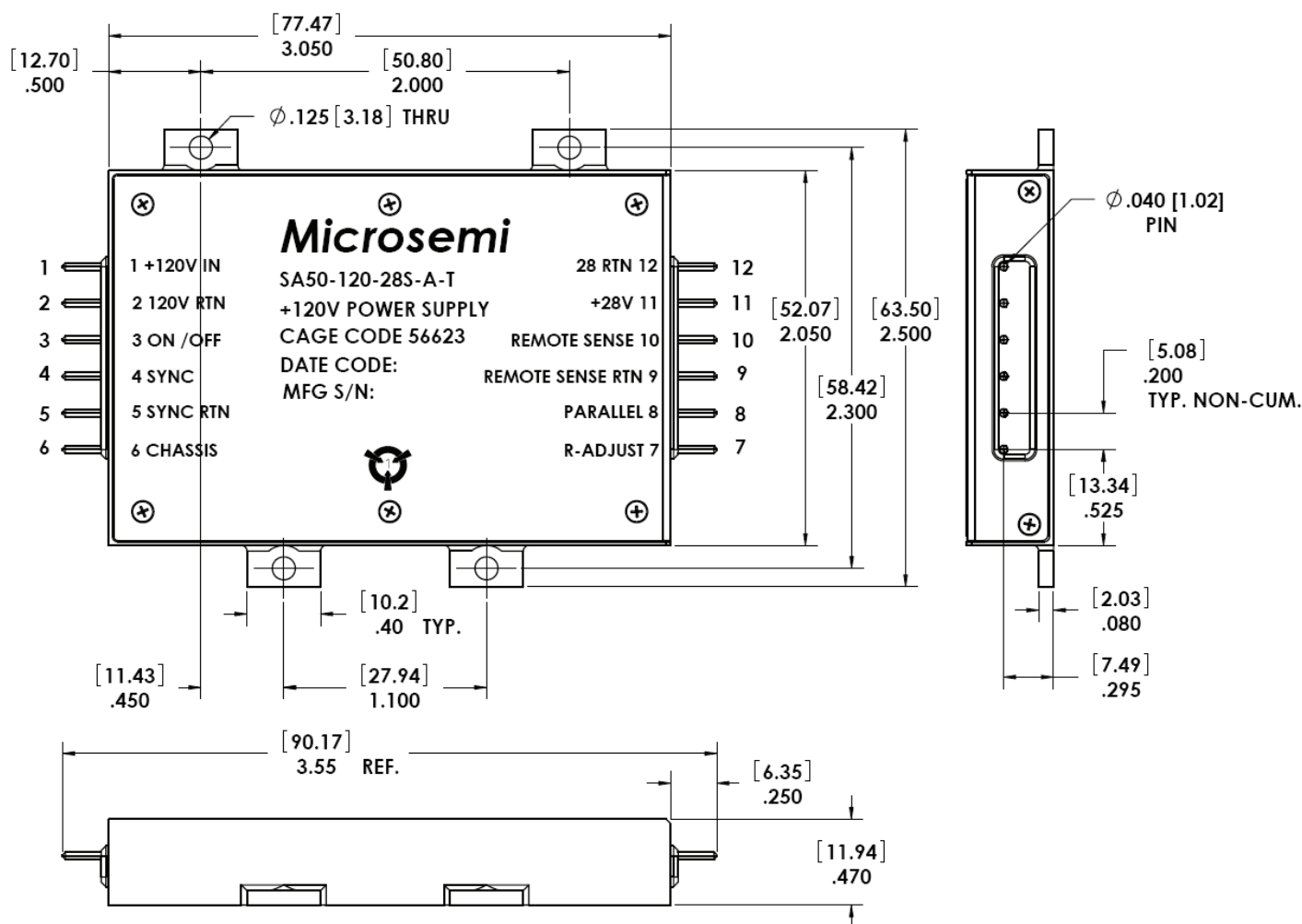


Figure 1

The surface on which an SA50 power supply is mounted is recommended to be flat to .005 in or less, with a surface roughness of 32 microinches or less. The mounting hole pattern and housing footprint for SA50 power supplies is shown in Figure 1.

The fasteners recommended for mounting of SA50 power supplies are 4-40 size fasteners, made from A-286 steel, used with NAS620C4 washers. Representative fasteners include NAS1101, NAS1352, or equivalent. The recommended torque is 6-8 in-lb.

MECHANICAL DIAGRAM & PINOUT - "A" Package



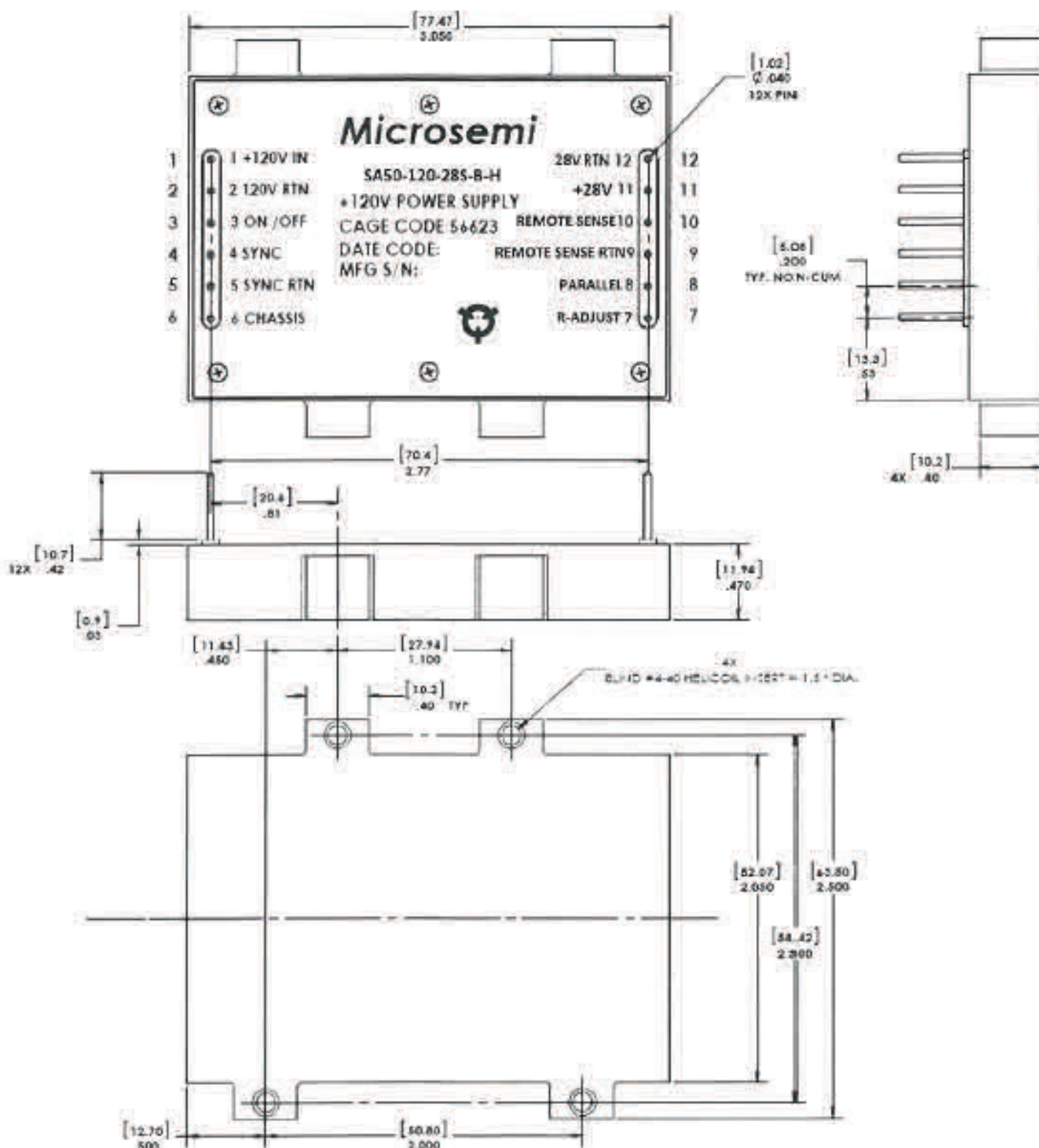
NOTES:

- 1.) PINS .040" (1.02 mm) DIAMETER.
- 2.) PINS MATERIAL: BRASS ALLOY 360, IAW ASTM B16.
PINS FINISH: ELECTRO-SOLDER .0005 MAX. THICK. (TIN LEAD) IAW SAE-AMS-P-81728.
- 3.) ALL DIMENSIONS IN INCHES (mm) TOLERANCES: .XX +/- .01 in. (.X +/- .254 mm)
.XXX +/- .005 in. (.XX +/- .127 mm).
- 4.) WEIGHT: 110 GRAMS MAX. (.24 LB MAX.)

PIN DESIGNATIONS

PIN No.	FUNCTION	PIN No.	FUNCTION
1	+120V IN	7	R-ADJUST
2	120V RTN	8	PARALLEL
3	ON/OFF	9	REMOTE SENSE RTN
4	SYNC	10	REMOTE SENSE
5	SYNC RTN	11	+28V
6	CHASSIS	12	28V RTN

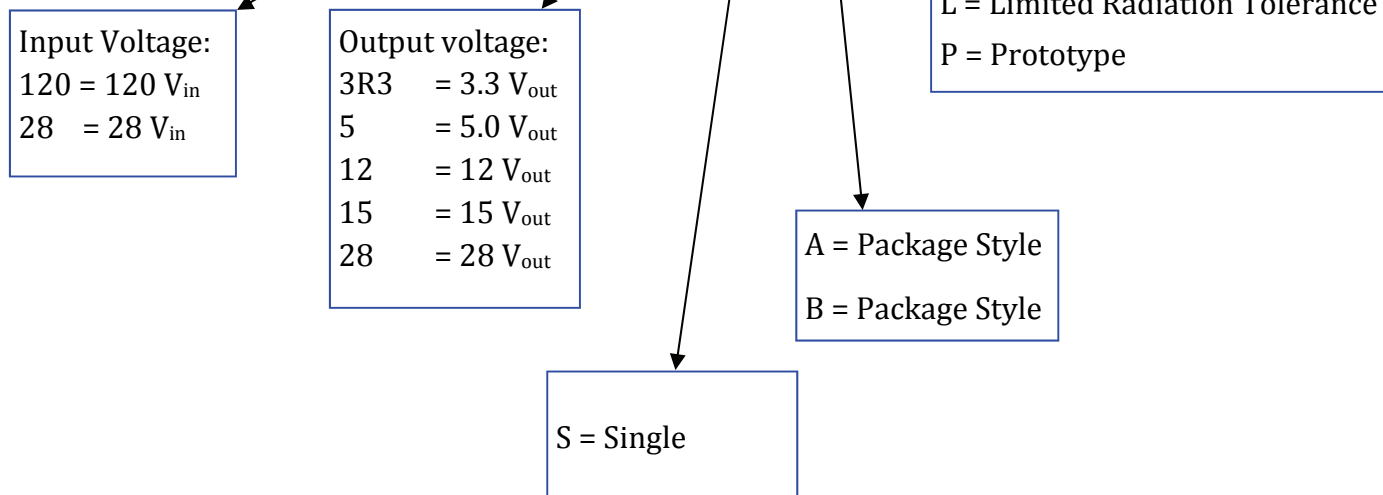
MECHANICAL DIAGRAM & PINOUT - "B" Package



- 1.) PINS .040" (1.02 mm) DIAMETER.
- 2.) PINS MATERIAL: BRASS ALLOY 360, IAW ASTM B16.
PINS FINISH: ELECTRO-SOLDER .0005 MAX. THICK. (TIN LEAD) IAW SAE-AMS-P-81728.
- 3.) ALL DIMENSIONS IN INCHES (mm) TOLERANCES: .XX +/- .01 in. (.X +/- .254 mm)
.XXX +/- .005 in. (.XX +/- .127 mm).
- 4.) WEIGHT: 120 GRAMS MAX. (0.26 LB MAX.)

PIN DESIGNATIONS

PIN No.	FUNCTION	PIN No.	FUNCTION
1	+120V IN	7	R-ADJUST
2	120V RTN	8	PARALLEL
3	ON/OFF	9	REMOTE SENSE RTN
4	SYNC	10	REMOTE SENSE
5	SYNC RTN	11	+28V
6	CHASSIS	12	28V RTN

ORDERING INFORMATION**SA50-120-5S-A-T****International Traffic in Arms Regulation (ITAR)**

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